

TMR7503-B

Unibody Low Temperature-Drift Current Sensor

Description

TMR7503-B is an open loop current sensor for accurate measurement of DC, AC, pulsed current and arbitrary waveform current with galvanic isolation between primary and secondary circuit.



- Low temperature coefficient
- High immunity to external interference
- Galvanic isolation
- Excellent linearity
- · Light weight and compact
- RoHS & REACH compliant





Applications

- DC motor drives
- Inverters and variable frequency drives (VFD)
- Uninterruptible power supplies (UPS)
- · Communication power supplies
- Battery management system (BMS)
- Switching power supplies
- Power supplies for welding application

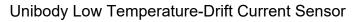
Selection Guide

Model	Primary Nominal Current	Primary Current Measuring Range
TMR7503-0500B	50 A	±150 A
TMR7503-1000B	100 A	±300 A
TMR7503-2000B	200 A	±600 A
TMR7503-3000B	300 A	±900 A
TMR7503-4000B	400 A	±950 A
TMR7503-5000B	500 A	±950 A
TMR7503-6000B	600 A	±950 A

Insulation and Environmental Characteristics

Parameters	Symbol	Typical	Unit
Dielectric Strength	V_{D}	5	kV(50Hz, 1min)
Insulation Resistance	R _{IS}	1000	МΩ
Creepage Distance	d_{CP}	7.7	mm
Clearance	d _{CL}	4.8	mm
Ambient Operating Temperature	T _A	-40 to +105	°C
Ambient Storage Temperature	T _{STG}	-40 to +105	°C
Mass	m	61	g







Catalogue

1. Specifications	03
2. Typical Output Characteristics	04
3. Typical Temperature Characteristics	05
4. Parameters Definition And Formula	07
5. Application Information	08
6 Dimensions	ΛΩ



1. Specifications

 $\rm T_A$ = +25 °C, $\rm V_{CC}$ = ±15 V, $\rm R_L$ = 10 k $\rm \Omega$, unless otherwise noted

A - 123 O, V _{CC} - ±13	v, IX I	O K12, UITIC 33 OUT	or wise rioled				
Parameter	Symbol	Сог	Min.	Typ.	Max.	Unit	
		Gene	ral Electrical Data				
		TMR75	TMR7503-0500B - 50 -			-	
Primary Nominal Current		TMR75	03-1000B	-	100	-	
		TMR7503-2000B		-	200	-]
	l _{PN}	TMR7503-3000B		-	- 300 - A	Α	
		TMR7503-4000B		-	400	-	
		TMR7503-5000B		-	500	-	
		TMR7503-6000B		-	600	-	
		TMR7503-0500B		-150	-	150	
		TMR7503-1000B		-300	-	300	
Drimon, Current		TMR7503-2000B		-600	-	600	
Primary Current Measuring Range	I _{PM}	TMR7503-3000B		-900	-	900	Α
weasuning realige		TMR7503-4000B		-950	-	950	
		TMR7503-5000B		-950	-	950	
		TMR75	03-6000B	-950	-	950	
			TMR7503-0500B	-	80.00	-	
			TMR7503-1000B	-	40.00	-	
			TMR7503-2000B	-	20.00	-	mV/A
Sensitivity	S	$I_P = 0 \text{ to } \pm I_{PN}$	TMR7503-3000B	-	13.33	-	
			TMR7503-4000B	-	10.00	-	
			TMR7503-5000B	-	8.00	-	
			TMR7503-6000B	-	6.67	-	
Output Voltage	V _{out}	$I_P = 0$ to $\pm I_{PM}$		-	V _{OE} + S × I _P	-	V
Supply Voltage	V _{cc}	±5 %		-	±15	-	V
Current Consumption	I _c	I _P = 0		-	±20	-	mA
Load Resistance	R_L	$I_P = 0 \text{ to } \pm I_{PN}$		1	10	-	kΩ
Load Capacitance	C _L	$I_P = 0 \text{ to } \pm I_{PN}$		-	100	-	pF
		Static	Performance Data				
	X _G	$T_A = +25 ^{\circ}\text{C}, \ I_P = 0 \text{ to } \pm I_{PN}$		-1	±0.5	1	% I _{PN}
Accuracy		$T_A = -40$ °C to +85 °C, $I_P = 0$ to $\pm I_{PN}$		-3	±1	3	
,		$T_A = -40$ °C to +105 °C, $I_P = 0$ to $\pm I_{PN}$		-3.5	±1.5	3.5	
Linearity Error	ε _L	$T_A = -40 \text{ °C to } +105 \text{ °C}, I_P = 0 \text{ to } \pm I_{PN}$		-	0.4	0.8	% I _{PN}
Symmetry	ε _{SYM}	$T_A = -40 \text{ °C to } +105 \text{ °C}, I_P = 0 \text{ to } \pm I_{PN}$		99	100	101	%
Sensitivity Error	ε _s	$T_A = -40 \text{ °C to } +105 \text{ °C}, I_P = 0 \text{ to } \pm I_{PN}$		-2	-	2	%
emperature coefficient of Voltage Output	TCV _{OUT}	$T_A = -40 ^{\circ}\text{C} \sim +105 ^{\circ}\text{C}$		-	300	-	PPM/°C
Offset Error	V _{OE}	$T_A = +25 ^{\circ}\text{C}, I_P = 0$ $T_A = -40 ^{\circ}\text{C} \text{ to } +105 ^{\circ}\text{C}, I_P = 0$		-20	±10	20	mV
				-60	±20	60	
Temperature coefficient of Offset Error	TCV _{OE}	$T_A = -40 ^{\circ}\text{C} \sim +105 ^{\circ}\text{C}$ $I_{PN} = 50\text{A}$ Other ranges		-	0.8	-	mV/°C
				-	0.4	-	
Hysteresis	V _{OH}	T _A = -40 °C to +1	-20	±10	20	mV	
		Dynami	c Performance Data				
Response Time	t _R	di/dt > 50 A/ μ s, 10% to 90% of I _{PN}		-	1	-	μs
Bandwidth	BW	-3	DC	180	-	kHz	



2. Typical Output Characteristics

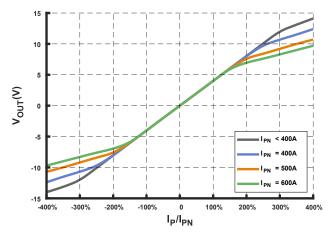


Figure 1. Output voltage versus primary current

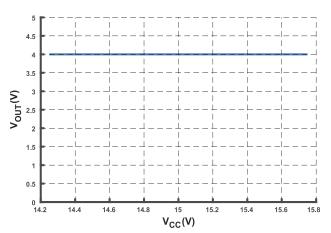


Figure 2. Output voltage versus supply voltage

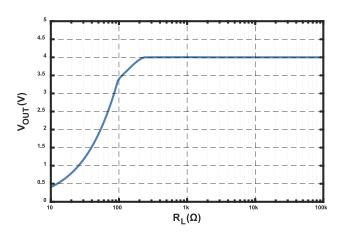


Figure 3. Output voltage versus load resistance $(@I_P=I_{PN})$

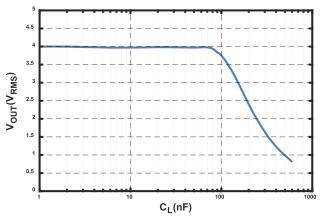


Figure 4. Output voltage versus load capacitance $(@I_P = I_{PN})$

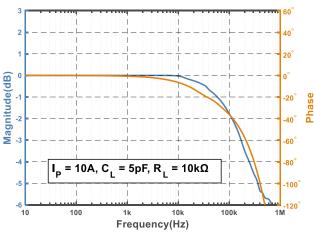
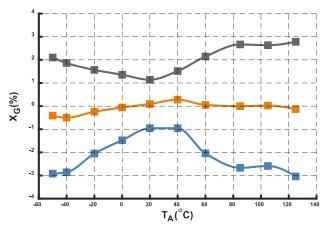


Figure 5. Bode plot of TMR7503-B



3. Typical Temperature Characteristics





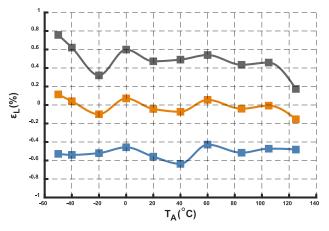
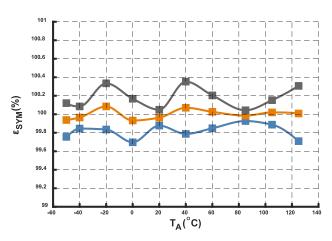


Figure 6. Total error versus ambient temperature

Figure 7. Linearity error versus ambient temperature



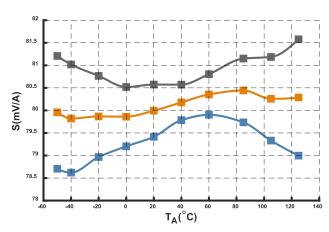
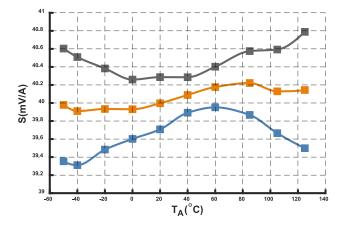


Figure 8. Symmetry versus ambient temperature

Figure 9. Sensitivity $@I_{PN} = 50 \text{ A versus ambient}$ temperature



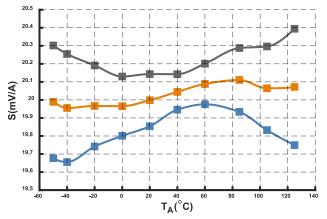


Figure 10. Sensitivity @I_{PN} = 100 A versus ambient temperature

Figure 11. Sensitivity $@I_{PN}$ = 200 A versus ambient temperature



Typical Temperature Characteristics



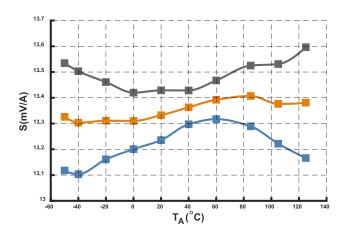


Figure 12. Sensitivity $@I_{PN}$ = 300 A versus ambient temperature

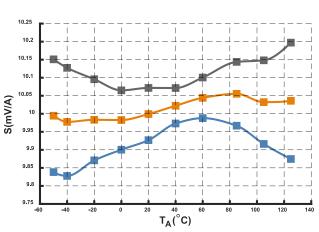


Figure 13. Sensitivity $@I_{PN}$ = 400 A versus ambient temperature

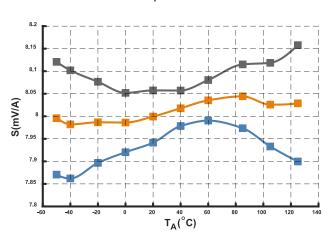


Figure 14. Sensitivity @I_{PN} = 500 A versus ambient temperature

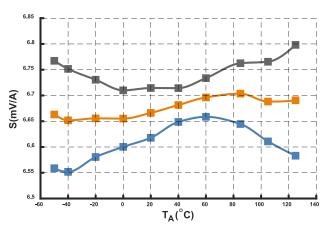


Figure 15. Sensitivity @I_{PN} = 600 A versus ambient temperature

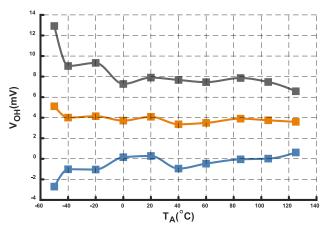


Figure 16. Hysteresis versus ambient temperature



4. Parameters Definition And Formula

1) Output Voltage

$$V_{OUT} = V_{OE} + S \times I_{P}$$

 V_{OUT} stands for current sensor output voltage at given primary current, V_{OE} stands for offset error, S stands for sensitivity, I_P stands for primary current.

2) Accuracy

$$X_{G} = MAX_{I_{P} \in [-I_{PN}, I_{PN}]} \left(\frac{V_{OUT} - (S \times I_{P})}{S \times I_{PN}} \times 100\% \right)$$

I_{PN} stands for nominal primary current

3) Sensitivity

$$S = \frac{V_{OUT(@ I_{PN})} - V_{OUT(@ -I_{PN})}}{2 \times I_{PN}}$$

 $V_{OUT_{\left(\tiny{\textcircled{0}} \mid_{PN} \right)}} \text{ and } V_{OUT_{\left(\tiny{\textcircled{0}} \mid_{PN} \right)}} \text{ stand for the voltage output at } I_{PN} \text{ and } \text{-}I_{PN} \text{ respectively.}$

4) Linearity

$$\varepsilon_{L} = \underset{I_{P} \in [-I_{PN}, I_{PN}]}{\text{MAX}} \left(\frac{V_{\text{OUT}} - (\overline{V}_{\text{OE}} + \overline{S} \times I_{P})}{S \times I_{PN}} \times 100\% \right)$$

 \overline{S} and \overline{V}_{OE} stand for the average values of the sensitivity and offset error.

5) Symmetry

$$\varepsilon_{\text{SYM}} = \left| \frac{V_{\text{OUT}(@ I_{\text{PN}})} - \overline{V}_{\text{OE}}}{V_{\text{OUT}(@ -I_{\text{DN}})} - \overline{V}_{\text{OE}}} \right| \times 100\%$$

6) Hysteresis

$$V_{OH} = MAX \Delta H$$

ΔH is the maximum residual voltage between full scale positive and negative nominal current.



5. Application Information

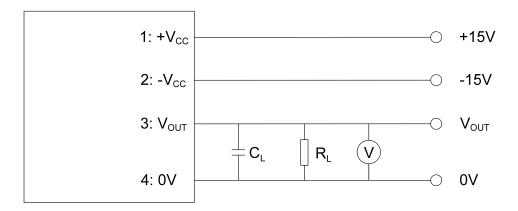


Figure 17. Connection diagram of TMR7503

Mounting Recommendation

1. Mounting method: Choose one of $3 \times \Phi$ 4.5 mm holes

1 × M4 copper or SS304 screw (recommended applied torque 0.75 N•m)

2. Primary through-hole dimensions: 20 mm × 10 mm

3. Secondary terminal: Molex 22041041 (previous 5045-04A series)

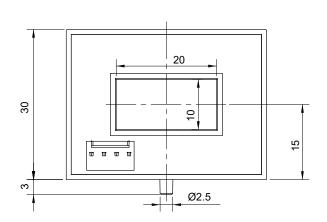
Crimp Housing: Molex 22011042, Crimping Terminal: Molex 08500113

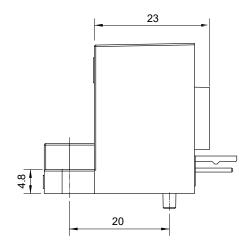
Remarks

- 1. V_{OUT} is positive when the primary current is in the same direction as the arrow indication on the label and vice versa.
- 2. Improper connection can cause permanent damage of the sensor.
- 3. Excessive capacitive load may cause the distortion of output signals when the primary frequency is too high. Please refer to Figure 4.
- 4. Sensor is customizable upon request.
- 5. Dynamic performances (di/dt and response time) are best with a single busbar completely filling the primary hole.



6. Dimensions





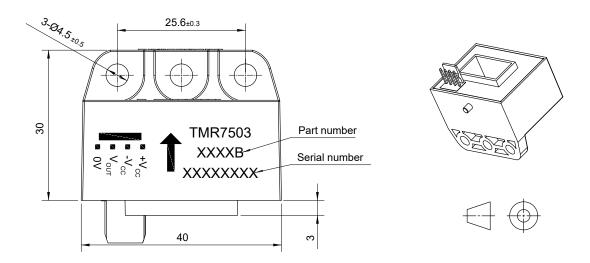


Figure 18. Sensor outline (unit: mm, tolerances for unmarked scales ±1 mm)

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